Vishay Siliconix

1 pC Charge Injection, 100 pA Maximum Leakage, +5 V / +3 V, SPDT Analog Switch

DESCRIPTION

The DG9431E is a monolithic CMOS switch designed for precision signal switching. The 17 Ω low voltage part exhibits low charge injection over the full signal range, low leakage, low parasitic capacitance, and fast switching.

The DG9431E can switch both analog and digital signals. Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off. Break-before-make switching is guaranteed.

The DG9431E offers 1 nW typical power consumption and 8 kV ESD (HBM), 1 kV ESD (CDM) tolerance. It is ideal for use in low voltage instruments and healthcare devices, fitting the circuits of low voltage ADC and DAC, sample and hold, analog front end gain control, and signal path switching. The DG9431E is available in 6-lead TSOP and 8-lead SOIC packages.

APPLICATIONS

- · Automatic test equipment
- · Process control and automation
- · Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- Sample-and-hold systems
- · Relay replacements
- Battery powered systems

FEATURES

- 1 pC charge injection
- Guaranteed 100 pA max. switch on leakage at 25 °C



RoHS

- 3.8 pF switch off and 7.8 pF switch on capacitances
- +2.7 V to +5 V single supply operation
- Low on-resistance R_{DS(on)}: 17 Ω (typ.) at 5 V
- t_{ON}: 32 ns, t_{OFF}: 10 ns switching time
- Typical power consumption: 1 nW
- Over voltage tolerance on logic control IN pin
- TTL / CMOS compatible
- ESD (HBM): > 8000 V, ESD (CDM): >1000 V
- Latch-up current: > 300 mA (JESD78)
- Available in TSOP-6 and SOIC-8

Note

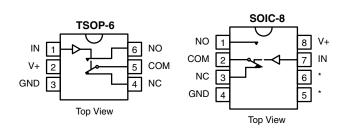
* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non-RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details.

BENEFITS

- Low charge injection and leakage
- · Low parasitic capacitance
- · Fast switching speed
- High ESD tolerance

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

*Not Connected



TRUTH TABLE					
LOGIC	NC	NO			
0	ON	OFF			
1	OFF	ON			

Note

 Logic "0" ≤ 0.8 V Logic "1" ≥ 2.4 V

ORDERING INFORMATION							
TEMP. RANGE	CONFIGURATION	PART NUMBER	PACKAGE	MINIUM ORDER / PACKAGING QUANTITY			
	C to +85 °C DG9431E 6-pin TSOP 8-pin SOIC	6-pin TSOP	DG9431EDV-T1-GE3	Tape and reel 3000 units			
-40 °C to +85 °C		9 nin 2010	DG9431EDY-T1-GE3	Tape and reel 2500 units			
		8-pin SOIC	DG9431EDY-GE3	Tube 500 units			



ABSOLUTE MAXIMUM RATINGS						
PARAMETER	LIMIT	UNIT				
Reference V+ to GND	Reference V+ to GND					
IN, COM, NC, NO ^a		-0.3 to (V+ + 0.3)	V			
Continuous current (any terminal)		± 20	mA			
Peak current (pulsed at 1 ms, 10 % duty cycle)	± 40					
ESD (HBM) (MIL-STD-883, method 3015)	> 8000	V				
ESD (CDM) (ANSI / ESDA / JEDEC® JS-002)	> 1000	7				
Latch up current, per JESD78	300	mA				
Storage temperature (D suffix)	-65 to +125	°C				
Power dissipation (packages) ^b	8-pin narrow body SOIC ^c	400	mW			
Fower dissipation (packages)	6-pin TSOP ^d	570	7 ''''			

Notes

- a. Signals on SX, DX, or INX exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6.5 mW/°C above 75 °C.
- d. Derate 7 mW/°C above 70 °C.

SPECIFICATIONS (V+	= 3 V)						
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. a	D SUFFIX -40 °C TO +85 °C			UNIT
		V+ = 3 V, \pm 10 %, V _{IN} = 0.8 V or 2.4 V $^{\rm e}$		MIN. c	TYP. b	MAX. c	
Analog Switch							
Analog signal range ^d	V _{ANALOG}		Full	0	-	3	V
Drain-source on-resistance	R _{DS(on)}	V_{NO} or $V_{NC} = 1.5 \text{ V}$, V+ = 2.7 V $I_{COM} = 5 \text{ mA}$	Room Full	-	35 -	50 65	
R _{DS(on)} match ^d	$\Delta R_{DS(on)}$	V_{NO} or $V_{NC} = 1.5 \text{ V}$	Room	-	0.4	2	Ω
R _{DS(on)} flatness ^f	R _{DS(on)} flatness	V _{NO} or V _{NC} = 1 V and 2 V	Room	-	4	8	
NO or NC off leakage current ^g	1	V_{NO} or $V_{NC} = 1 \text{ V} / 2 \text{ V}$, $V_{COM} = 2 \text{ V} / 1 \text{ V}$	Room	-100	5	100	
NO of NC off leakage current 9	I _{NO/NC(off)}	v_{NO} or $v_{NC} = 1$ $v / 2$ v , $v_{COM} = 2$ $v / 1$ v	Full	-5000	-	5000	
COM off leakage current ^g	1	$V_{COM} = 1 \text{ V} / 2 \text{ V}, V_{NO} \text{ or } V_{NC} = 2 \text{ V} / 1 \text{ V}$	Room	-100	5	100	pA
COM on leakage current 9	I _{COM(off)}	$v_{COM} = 1 \text{ V } / 2 \text{ V}, v_{NO} \text{ Or } v_{NC} = 2 \text{ V } / 1 \text{ V}$	Full	-5000	-	5000	
Channel-on leakage current ^g	I _{COM(on)}	$V_{COM} = V_{NO}$ or $V_{NC} = 1 \text{ V} / 2 \text{ V}$	Room	-200	5	200	
Charmer-on leakage current 9			Full	-10 000	-	10 000	
Digital Control							
Input current	I _{INL} or I _{INH}		Full	-	0.001	-	μΑ
Dynamic Characteristics							
Turn-on time	tau		Room	-	43	120	
rum-on ume	t _{ON}		Full	-	-	200	ns
Turn-Off Time	toff	V_{NO} or $V_{NC} = 1.5 V$	Room		16	50	
Turn-Oil Time	ıOFF		Full	-	i	120	
Break-before-make time	t _d		Room	3	26	-	
Charge injection	Q_{INJ}	C_L = 1 nF, V_{gen} = 0 V, R_{gen} = 0 Ω	Room	-	-0.28	-	рC
Off-isolation	O _{IRR}	$R_1 = 50 \Omega$, $C_1 = 5 pF$, $f = 1 MHz$	Room	-	-80	-	dB
Crosstalk	X_{TALK}	$n_L = 50 \Omega_2, O_L = 5 \text{ pr}, I = 1 \text{ Winz}$	Room	-	-108	-	иБ
Source off capacitance	C _{S(off)}	f = 1 MHz	Room	-	4	-	nE.
Channel-on capacitance	C _{D(on)}	I = I IVIПZ	Room	-	8	-	pF
Power Supply							
Power supply range	V+			2.7	-	5.5	V
Power supply current	I+	$V+ = 3.3 \text{ V}, V_{IN} = 0 \text{ V or } 3.3 \text{ V}$		-	0.0003	1	μΑ



Vishay Siliconix

SPECIFICATIONS (V+	= 5 V)						
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. a	D SUFFIX -40 °C to +85 °C			UNIT
		V+ = 5 V, \pm 10 %, V $_{IN}$ = 0.8 V or 2.4 V e		MIN. c	TYP. b	MAX. c	
Analog Switch							
Analog signal range ^d	V _{ANALOG}		Full	0	ı	5	V
Drain-source on-resistance	R _{DS(on)}	V_{NO} or V_{NC} = 3.5 V, V+ = 4.5 V I_{COM} = 5 mA	Room Full	-	17	25 35	
R _{DS(on)} match ^d	$\Delta R_{DS(on)}$	V_{NO} or $V_{NC} = 1.5 \text{ V}$	Room	-	0.4	2	Ω
R _{DS(on)} flatness ^f	R _{DS(on)} flatness	V_{NO} or V_{NC} = 1 V, 2 V, and 3 V	Room	-	3.5	6	
NO or NC off leakage current	1	V _{NO} or V _{NC} = 1 V / 4 V, V _{COM} = 4 V / 1 V	Room	-100	10	100	
NO of NC off leakage current	I _{NO/NC(off)}	v_{NO} or $v_{NC} = 1$ $v / 4$ v , $v_{COM} = 4$ $v / 1$ v	Full	-5000	-	5000	
COM off lookeds assument		$V_{COM} = 1 \text{ V} / 4 \text{ V}, V_{NO} \text{ or } V_{NC} = 4 \text{ V} / 1 \text{ V}$	Room	-100	10	100	pA
COM off leakage current	I _{COM(off)}		Full	-5000	-	5000	
Channel on leakage assurent	I _{COM(on)}	$V_{COM} = V_{NO} \text{ or } V_{NC} = 1 \text{ V} / 4 \text{ V}$	Room	-200	-	200	
Channel-on leakage current		$\mathbf{v}_{COM} = \mathbf{v}_{NO} \text{ or } \mathbf{v}_{NC} = 1 \text{ v / 4 v}$	Full	-10 000	-	10 000	
Digital Control							
Input current	I _{INL} or I _{INH}		Full	-	0.001	ı	μΑ
Dynamic Characteristics							
Turn-on time	t _{ON}		Room	-	32	75	ns
Turri-ori time			Full	-	ı	150	
Turn-off time	t _{OFF}	V_{NO} or $V_{NC} = 3 V$	Room	-	10	50	
rum-on time			Full	-	ı	100	
Break-before-make time	t _d		Room	3	22	-	
Charge injection	Q_{INJ}	C_L = 1 nF, V_{gen} = 0 V, R_{gen} = 0 Ω	Room	-	-0.78	-	рС
Off-isolation	O _{IRR}	$R_1 = 50 \Omega$, $C_1 = 5 pF$, $f = 1 MHz$	Room	-	-80	-	٩D
Crosstalk	X _{TALK}	$H_L = 50 \Omega_2$, $G_L = 5 \text{ pF}$, $I = 1 \text{ MHz}$	Room	-	-108	-	dB
NC and NO capacitance	C _(off)	f = 1 MHz	Room	-	3.8	-	nΕ
Channel-on capacitance	C _{D(on)}	I = I IVI Z	Room	-	7.8	-	pF
Power Supply							
Power supply range	V+			2.7	-	5.5	V
Power supply current	l+	$V+ = 5.5 V$, $V_{IN} = 0 V$ or $5.5 V$		-	0.0004	1	μA

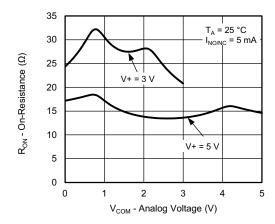
Notes

- a. Room = 25 °C, Full = as determined by the operating suffix.
- b. Typical values are for design aid only, not guaranteed nor subject to production testing.
- c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- d. Guarantee by design, nor subjected to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. Difference of min and max values.
- g. Guaranteed by 5 V leakage testing, not production tested.

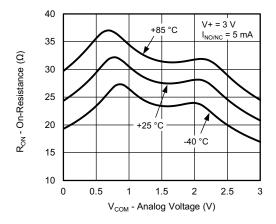
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



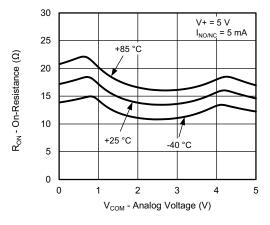
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



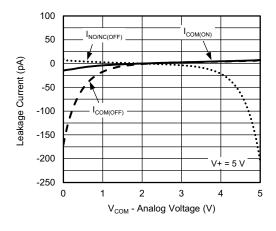
On-Resistance vs. Analog Voltage



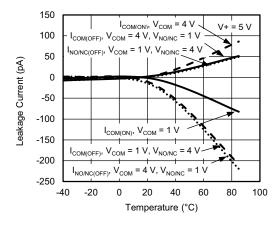
On-Resistance vs. Analog Voltage



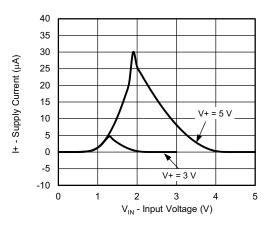
On-Resistance vs. Analog Voltage



Leakage Current vs. Analog Voltage



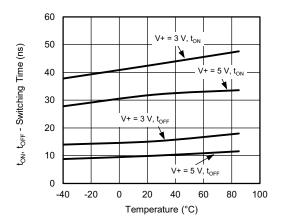
Leakage Current vs. Temperature



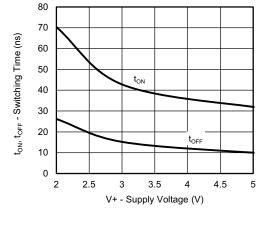
Supply Current vs. Input Voltage



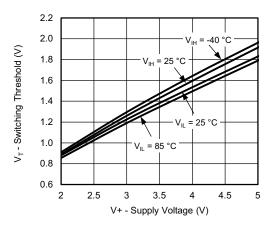
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



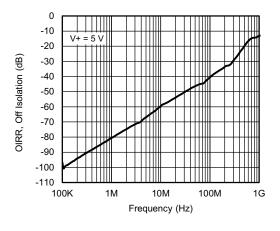
Switching Time vs. Temperature



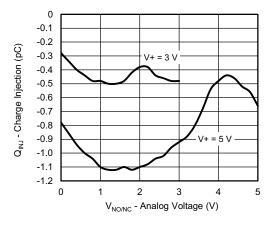
Switching Time vs. Supply Voltage



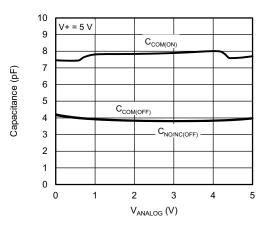
Switching Threshold vs. Supply Voltage



OIRR, Off Isolation vs. Frequency



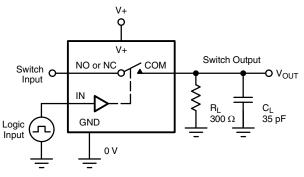
Charge Injection vs. Analog Voltage



Capacitance

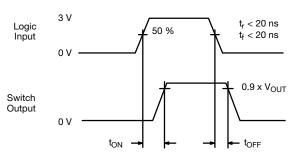


TEST CIRCUITS



C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$



Logic "1" = switch on Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time

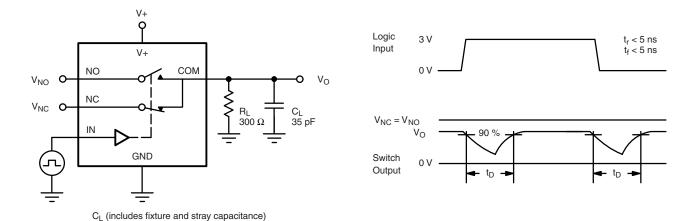


Figure 2. Break-Before-Make Interval

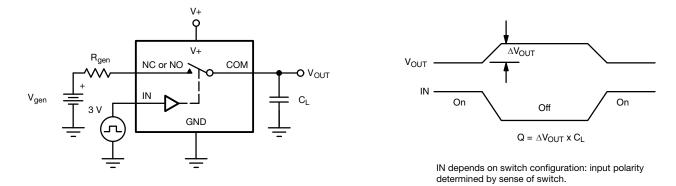


Figure 3. Charge Injection

TEST CIRCUITS

Off Isolation = 20 log $\frac{V_{NC/NC}}{V_{COM}}$

Figure 4. Off-Isolation

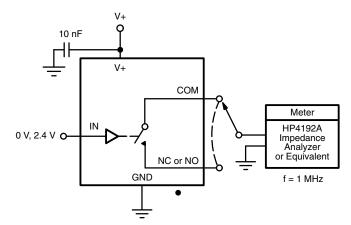


Figure 5. Channel Off/On Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg276459.



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INCHES			
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27	1.27 BSC) BSC		
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I. 11-Sep-06						

DWG: 5498

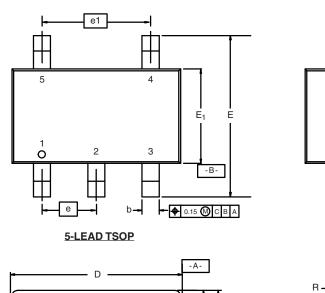
Document Number: 71192 www.vishay.com 11-Sep-06

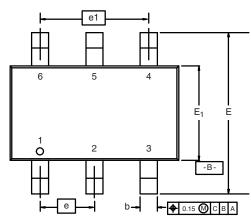




TSOP: 5/6-LEAD

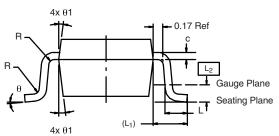
JEDEC Part Number: MO-193C





6-LEAD TSOP

D A₂ A
Seating Plane



	MIL	LIMETER	RS	ı	NCHES		
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
A ₁	0.01	-	0.10	0.0004	-	0.004	
A ₂	0.90	-	1.00	0.035	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	0.120	0.122	
Е	2.70	2.85	2.98	0.106	0.112	0.117	
E ₁	1.55	1.65	1.70	0.061	0.065	0.067	
е		0.95 BSC		(0.0374 BSC	;	
e ₁	1.80	1.90	2.00	0.071	0.075	0.079	
L	0.32	-	0.50	0.012	-	0.020	
L ₁		0.60 Ref		0.024 Ref			
L ₂		0.25 BSC		0.010 BSC			
R	0.10	-	-	0.004	-	-	
θ	0°	4°	8°	0°	4°	8°	
θ_1	7° Nom 7° Nom						
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540							

Document Number: 71200 www.vishay.com 18-Dec-06 uww.vishay.com



RECOMMENDED MINIMUM PADS FOR SO-8



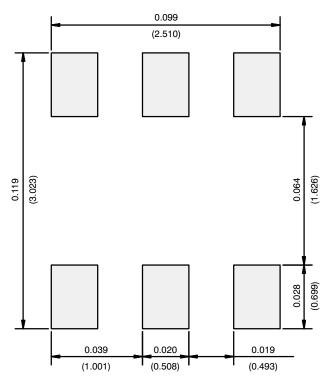
Recommended Minimum Pads Dimensions in Inches/(mm)

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VISHAY.

RECOMMENDED MINIMUM PADS FOR TSOP-6



Recommended Minimum Pads Dimensions in Inches/(mm)

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